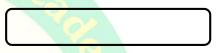
[ELECTRONICS & TELECOMMUNICATION ENGINEERING (OBJECCTIVE TYPE) PAPER – I



INSTRUCTIONS

- 1. IMMEDIATELY AFTER THE COMMENCEMENT OF THE EXAMINATION, YOU SHOULD CHECK THAT THIS TEST BOOKLET DOES NOT HAVE ANY UNPRINTED OR TORN OR MISSING PAGES OR ITEMS, ETC. IF SO, GET IT REPLACED BY A COMPLETE TEST BOOKLET.
- 2. ENCODE CLEARLY THE TEST BOOKLET SERIES **A**, **B**, **C** OR **D** AS THE CASE MAY BE IN THE APPROPRIATE PLACE IN THE ANSWER SHEET.
- 3. You have to enter your Roll Number on the Test Booklet in the Box provided alongside. *DO NOT* write *anything else* on the Test Booklet



- 4. This Test Booklet contains 120 items (questions), 60 in PART A and 60 in PART B. Each item comprises four responses (answers). You will select the response which you want to mark on the Answer Sheet. In case you feel that there is more than one correct response, mark the response which you consider the best. In any case, choose ONLY ONE response for each item.
- 5. You have to mark all your responses *ONLY* on the separate Answer Sheet provided. See directions in the Answer Sheet.
- 6. All items carry equal marks
- 7. Before you proceed to mark in the Answer Sheet the response to various items in the Test Booklet, you have to fill in some particulars in the Answer Sheet as per instructions sent to you with your Admission Certificate.
- 8. After you have completed filling in all your responses on the Answer Sheet and the examination has concluded, you should hand over to the Invigilator *only the Answer Sheet*. You are permitted to take away with you the Test Booklet.
- 9. Sheets for rough work are appended in the Test Booklet at the end.

10. Penalty for wrong answers:

THERE WILL BE PENALTY FOR WRONG ANSWERS MARKED BY A CANDIDATE IN THE OBJECTIVE TYPE QUESTION PAPERS.

- (i) There are four alternatives for the answer to every question. For each question for which a wrong answer has been given by the candidate, **one-third (0.33)** of the marks assigned to that question will be deducted as penalty.
- (ii) If a candidate gives more than one answer, it will be treated as a **wrong answer** even if one of the given answers happiness to be correct and there will be same penalty as above to that question.
- (iii)If a question is left blank, i.e. no answer is given by the candidate, there will be **no penalty** for that question.

01.	 The I-V characteristics of a tunnel diode exhibit (a) current-controlled negative resistance (b) voltage-controlled negative resistance (c) temperature-controlled positive resistance (d) current-controlled positive resistance 						
Ans	: (b)						
02.	A gate to drain-connected enhancemen (a) an active load (c) a three-terminal device						
Ans							
03.	Thermal runway is not possible in FET (a) the drain current increases (c) the mobility decreases	F because, as the temperature (b) the mobility increases (d) the transconductance incr					
Ans	: (c)						
04.	The output impedance of a BJT under	common-collector configurat (c) medium					
Ans	(a) low (b) high (a)	(c) medium	(d) very high				
05.	Consider the following statements rela 1. Its operation depends on the flow of 2. It is less noisy than BJT 3. It has poor thermal stability 4. It is relatively immune to radiation The correct statements are (a) 1, 2, 3 and 4 (c) 2 and 4 only						
Ans	: (c)						
06.	For common-collector amplifier, the c (a) $1+h_{fe}$ (b) $\frac{1+h_{fe}}{1+h_{oe}R_{L}}$	(c) $\frac{1+h_{fe}}{(d)}$ (d) $\frac{1}{(d)}$	$h + h_{fe}$ $h_{fe} R_{I}$				
Ans		li oe li ie	ie K _L				
07. Ans	Consider the following statements: 1. Speed of operation of MOSFET is m 2. SCRs have lower power loss than M 3. The current in conducting state can 4. MOSFET is not a current triggered of The correct statements are (a) 1 and 4 only (c) 2 and 3 only : (a)	IOSFETs. easily be controlled through t					

Match List-I with List-II and select the correct answer using the code given below the 08. Lists:

	Lists: List – I						List II				
	A. di / dt rating limits						List – II 1. Snubber circuit				
		.5		2. Heat sink							
B. dv / dt rating C. i ² t limit							ries rea				
						3. Sei 4. Fu					
D. Junction temperature limit				l	4. I'u	50					
Cod	es:										
000	•	Α	В	С	D		Α	В	С	D	
	(a)	2	4	1	3	(b)	3	4	1	2	
	(c)	2	1	4	3	(d)	3	1	4	2	
Ans	: (d)					041					
09.	An SC	CR can	be turne	ed off							
	(a) by	passing	g a nega	tive pul	se to its	s gate					
	(b) by	remov	ing the	gate sup	ply						
		reverse	-		1.						
					ough g	ate <mark>to</mark> be	come z	ero			
Ans	: (c)	97			00						
							man				
10.	Body	effect in	n MOS	FETs rea	sults in						
	(a) inc	crease in	n the va	lue of tr	anscon	ductance	e				
	(b) ch	ange in	the val	ue of thi	reshold	voltage					
						ductanc	e				
	(d) ind	crease i	n the va	lue of o	utput re	esistance	:				
Ans	: (b)										
						1					
11.	The et	fficienc	y of an	LED for	r genera	ating ligl	ht is di	rectly p	roportio	nal to the	
	(a) ap	plied vo	oltage				(b) c	urrent i	njected		
	(c) ter	nperatu	re				(d) l	evel of	doping		
Ans	Ans: (b)										
	my my former										
12.	A sign	nal f(t) i	s descri	ibed as				× 1			
	f(t) =	[1- t] v	when t	$ \leq 1$				ser.			
	=	0 w	hen t	>1							
	This r	epresen	ts the u	nit							
	(a) sir	nc funct	ion						unction		
	(c) sig	gnum fu	nction	CI		(d) pa	araboli	c function	on		
Ans	: (b)					/)),	J		

13. Match List – I with List – II and select the correct answer using the code given below the Lists:

List – I							List – II			
	A. Eve	en signa	ıl				1. x	$(n) = \left(\frac{1}{4}\right)$	$\left(\int_{-\infty}^{n} u(n) \right)^{n}$	
	B. Cau	ısal sigi	nal				2. x	(-n) = x	x(n)	
	C. Peri	iodic si	gnal				3. x(t)u(t)		
	D. Ene	ergy sig	nal				4. x	(n) = x((n + N)	
	Codes									
		Α	В	C 4 3	D		Α	B 3 4	С	D
	(a)	2	3	4	1	(b)	1	3	4	2 2
		2	4	3	1	(d)	1	4	3	2
Ans	: (a)									
14.	The pe	rio <mark>d of</mark>	the sig	nal x(t)	= 10sii	n12 πt+4	cos 18	πt is		
	(a) $\frac{\pi}{4}$			(b) $\frac{1}{6}$	- - 		(c) $\frac{1}{2}$	l	(d) $\frac{1}{3}$	
Ans	: (d)					1/2				
	4 4.				C .				2t	0 10 1 1

- 15. A linear time-invariant system has an impulse response of e^{2t} , t > 0. If the initial conditions are zero and the input is e^{3t} , the output for t > 0 is (a) $e^{3t} - e^{2t}$ (b) e^{5t} (c) $e^{3t} + e^{2t}$ (d) e^{t} Ans : (a)
- 16. A system described by the following differential equation is initially at rest and then excited by the input x(t) = 3 u(t):

$$\frac{d^2 y}{dt^2} + 4\frac{dy}{dt} + 3y = x(t)$$
. The output y(t) is
(a) $1 - 1.5e^{-t} + 0.5e^{-3t}$
(b) $1 - 0.5e^{-t} + 1.5^{-3t}$
(c) $1 + 1.5e^{-t} - 0.5e^{-3t}$
Ans : (a)
(b) $1 - 0.5e^{-t} + 1.5e^{-3t}$
(c) $1 + 0.5e^{-t} + 0.5e^{-3t}$
(c) $1 + 0.5e^{-t} + 0.5e^{-3t}$

17. The natural response of an LTI system described by the difference equation y(n) - 1.5y(n-1) + 0.5y(n-2) = x(n) is

(a) $y(n) = 0.5u(n) - 2(0.5)^n u(n)$ (b) $y(n) = 0.5u(n) - (0.5)^n u(n)$ (c) $y(n) = 2u(n) - 0.5(0.5)^n u(n)$ (d) $y(n) = 2u(n) - (0.5)^n u(n)$

Ans: (d)

18. Consider a system described by the state model

$$X = \begin{bmatrix} 2 & 1 \\ -1 & 2 \end{bmatrix} X + \begin{bmatrix} 1 \\ 1 \end{bmatrix} U$$
$$Y = \begin{bmatrix} 1 & 1 \end{bmatrix} X$$

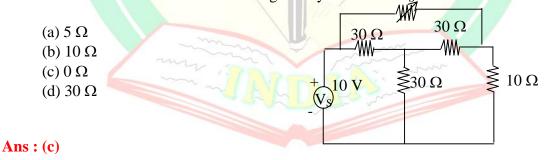
The system is

- (a) controllable but not observable
- (c) both controllable and observable

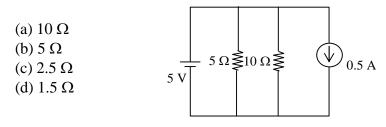
(b) uncontrollable and observable

(d) neither controllable nor observable

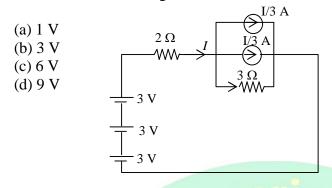
19. The system represented by the state-variable model $X = \begin{bmatrix} 0 & -1 \\ 1 & -2 \end{bmatrix} X + \begin{bmatrix} 1 \\ 2 \end{bmatrix} U \text{ is}$ (a) oscillatory (b) critically damped (d) under-damped (c) over-damped Ans: (b) 20. A second-order system rep-represented by state variables has $A = \begin{bmatrix} -2 & -4 \\ 1 & 0 \end{bmatrix}$ The values of natural frequency and damping factor are respectively (d) 0.5 and 2 (a) 2 and 0.5 (b) 2 and 1 (c) 1 and 2 Ans: (a) 21. The steady-state value of the currents $i_1(t)$ and $i_2(t)$ in the circuit are (a) 2 A and 1 A 5Ω (b) 1.5 A and 1.5 A $i_2(t)$ (c) 1 A and 2 A $i_1(t)$ (d) 1 A and 1 A 2 H ž 1 H 15 V Ans: (a) 22. In the circuit, the value of the resistance R_s required for maximum power transfer from the 10 V source to the 10 Ω load is given by Rs



23. The total resistance faced by the voltage source having zero internal resistance in the circuit is

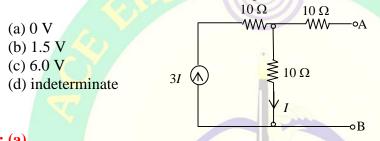


24. In the circuit, the voltage across 3 Ω resistance is



Ans: (b)

25. In the circuit shown, Thevenin's voltage as seen from the terminals AB is



Ans: (a)

26. A random variable is known to have a cumulative distribution function

$$F_{x}(x) = U(x)\left(1 - \frac{x^{2}}{b}\right) \text{ its density function is}$$

(a) $U(x)\frac{2x}{b}\left(1 - e^{-x^{2}/b}\right)$
(b) $U(x)\frac{2x}{b}e^{-x^{2}/b}$
(c) $U(x)\left(1 - \frac{x^{2}}{b}\right)U(x)$
(d) $\left(1 - \frac{x^{2}}{b}\right)U(x) + e^{-x^{2}/b}$

Question framing is wrong. However from the available information correct answer is (c)

27. The probability cumulative distribution function must be monotone and (a) increasing (b) decreasing (c) non-increasing (d) non-decreasing

Ans: (d)

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28. The step response of a discrete time system with transfer function

. .

$$H(Z) = \frac{10}{(Z-1)(Z+2)}$$
 is given by
(a) $\frac{-10}{9} + \frac{10}{3}n + \frac{10}{9}(-2)^n$ (b) $-5 + \frac{n}{2} + (-2)^n$
(c) $\frac{-7}{9} + \frac{5}{3}n + (-3)^n$ (d) $-2 + 5(1-2^n)$

Ans: (a)

29. The Z-transform corresponding to the Laplace transform function

$$G(s) = \frac{10}{s(s+5)}$$
 is
(a) $\frac{2Ze^{-5Z}}{(Z-1)(Z-e^{-T})}$ (b) $\frac{2(1-e^{-5Z})Z}{(Z-1)(Z-e^{-5T})}$
(c) $\frac{e^{-5T}}{(Z-1)^2}$ (d) $\frac{e^{-T}}{Z(Z-e^{-3T})}$

30. The difference equation for a system is given by y(n+2) + y(n+1) + 0.16y(n) = x(n+1) + 0.32x(n)The transfer function of the system is (a) $\frac{Z+0.32}{Z^2+Z+0.16}$

(c)
$$\frac{Z+0.32}{Z^2+0.16}$$

(b) $\frac{1}{Z^2 + Z + 0.16}$ (d) $\frac{Z + 2 + 0.10}{(Z - 1)(Z^2 + Z + 0.16)}$

(d) $H(e^{j\omega}) * H_1(e^{j\omega}) = \delta(\omega)$

Ans: (a)

- The discrete time system described by $y(n) = x(n)^2$ is 31. (a) causal and linear (b) causal and non-linear (c) non-causal and linear (d) non-causal and non-linear Ans: (b)
- The impulse response of a discrete time system is given by 32.

$$h(n) = \frac{1}{2} (u[n] + u[n-2])$$

The magnitude of the response can be expressed as

(a) $|\cos \Omega|$ (b) $\cos \Omega$ (c) $|\sin \Omega|$

Ans: (a)

 $H(e^{j\omega})$ is the frequency response of a discrete time LTI system and $H_1(e^{j\omega})$ is the 33. frequency response of its inverse function. Then (b) $H(e^{j\omega})H_1(e^{j\omega})=\delta(\omega)$

(a) $H(e^{j\omega})H_1(e^{j\omega})=1$ (c) $H(e^{j\omega}) * H_1(e^{j\omega}) = 1$

Ans: (a)

With the following equations, the time-invariant systems are 34.

1.
$$\frac{d^2 y(t)}{dt^2} + 2t \frac{d}{dt} y(t) + 5y(t) = x(t)$$

2. $y(t) = e^{-2x(t)}$
3. $y(t) = \left[\frac{d}{dt}x(t)\right]^2$
4. $y(t) = \frac{d}{dt}[e^{-2t}x(t)]$
(a) 1 and 2 (b) 1 and 4

(c) 2 and 3

(d) 3 and 4

(d) sin Ω

Ans: (c)

35. If F(s) and G(s) are the Laplace transforms of f(t) and g(t), then their product F(s). G(s) = H(s), where H(s) is the Laplace transform of h(t), is defined as

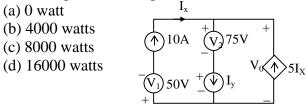
(a) (f.g)(t)(c) Both (a) and (b) are correct

(b) $\int_{0}^{t} f(\ddagger)g(t-\ddagger)dg\ddagger$ (d) f(t).g(t)

Ans: (b)

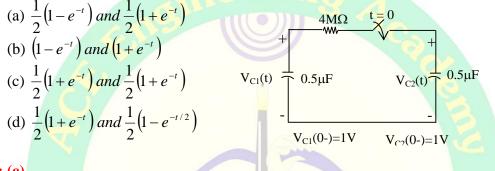
36.	Consider a system with transfer function	
	$3s^2 - 2$	
	$H(s) = \frac{3s^2 - 2}{s^2 + 3s + 2}$	
	The step response of the system is given by	
	(a) $C(t) = 5e^{-2t} e^{-t}$	(b) $C(t) = 3\delta(t) = 10e^{-2t} + e^{-t}$
	(a) $C(t) = 5e^{-2t} - e^{-t} - 1$ (c) $C(t) = 4e^{-t} - e^{-2t} - 1$	(b) $C(t) = 3\delta(t) - 10e^{-2t} + e^{-t}$ (d) $C(t) = 2(1-e^{-2t})$
Ang .		$(u) C(t) = 2(1-e^{-t})$
Ans :		
27	The Fourier transform of a reatengular pulse i	
37.	The Fourier transform of a rectangular pulse i	
	(a) another rectangular pulse	(b) triangular pulse
A	(c) sinc function	(d) impulse function
Ans :		
20	The function which has its Fourier transform	Lonloss transform and 7 transform unity
38.	The function which has its Fourier transform,	Laprace transform and Z-transform unity
	is (a) Coussian (b) impulse	(a) since (d) mulas
	(a) Gaussian (b) impulse	(c) sinc (d) pulse
Ans :		
20	The property of Fourier transformer which stat	as that the compression in time domain is
39.	The property of Fourier transforms which stat equivalent to expansion in the frequency dom	
	(a) duality	(b) scaling (d) fraguency shifting
Ans :	(c) time scaling	(d) frequency shifting
Ans :		
40	A manufactor is since $h_{1}(x) = 10 \sin 2 - 100t$	What will be the maniful of the second
40.	A waveform is given by $v(t) = 10\sin 2\pi 100t$.	what will be the magnitude of the second
	harmonic in its Fourier series representation?	(c) 100 V (d) 200 V
A	(a) 0 V (b) 20 V	(c) 100 v (d) 200 v
Ans :	(a)	
41.	They anin's acquivelent resistance as seen from	the terminals AP for the sirewit is
41.	The venin's equivalent resistance as seen from $1k\Omega$	The terminals AB for the circuit is
		1990
	(u) 1 KEE	
	(b) 10Ω I	
	(c) 100Ω + $99I$	
	(d) 10 kΩ $\frac{1V(V_3)}{-1}$	
	└─── ० B	
Ans :	(b)	

The total power developed in the circuit, if $V_0 = 125$ V is 42.



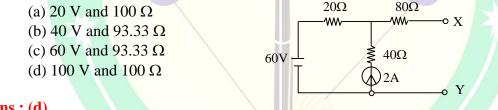
Ans: (c)

In the circuit given, the switch is closed at t = 0+. The initial voltages on the capacitors 43. are indicated in the diagram. The voltages $V_{cl}(t)$ and $v_{c2}(t)$ for $t \ge 0$ are respectively



Ans: (c)

44. In the circuit, Thevenin's voltage and resistance across the terminals XY will be



Ans: (d)

A voltage of 24 V DC is applied through switch S to an R-L series circuit. Switch S 45. was initially open. At time t = 0, switch is closed. The rate of change of current through the resistor is 8 A/s, while the current through the inductor is 8 A. If the value of the inductor is 1 H, then for this condition the value of the resistor will be (a) 1 Ω (b) 2Ω (c) 3Ω (d) 4Ω

Ans:(b)

The steady-state response of a network to the excitation $V\cos(\omega t + \phi)$ may be found in 46. three steps. The first two steps are as follows:

1. Determining the response of the network to the excitation $e^{j\omega t}$

2. Multiplying the above response by $\overline{V} = Ve^{jw}$

The third step is

- (a) finding the complex conjugate of the expression after step 2
- (b) finding the magnitude of the expression after step 2
- (c) finding the real part of the expression after step 2
- (d) finding the imaginary part of the expression after step 2

47.

The unit step response y(t) of a linear system is $y(t) = (1 - 3e^{-t} + 3e^{-2t}) u(t)$ For the system function, the frequency at which the forced response become zero is

(a)
$$\frac{1}{\sqrt{2}} rad / s$$
 (b) $\frac{1}{2} rad / s$ (c) $\sqrt{2} rad / s$ (d) 2 rad/s

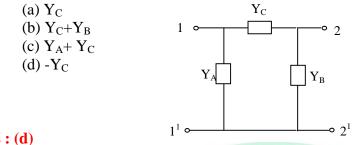
Ans: (c)

For a given connected network and for a fixed tree, the fundamental loop matrix is 48. given by

8	
$\begin{bmatrix} 1 & 0 & 1 & 0 \end{bmatrix}$	
$B = \begin{bmatrix} 0 & 1 & 0 & 0 & -1 \end{bmatrix}$	
$B = \begin{bmatrix} 1 & 0 & 0 & 1 & 0 & 0 \\ 0 & 1 & 0 & 0 & 0 & -1 \\ 0 & 0 & 1 & 1 & -1 & -1 \end{bmatrix}$	
The fundamental cut-set matrix Q corresponding	
(a) $Q = \begin{bmatrix} -1 & 0 & -1 & 1 & 0 & 0 \\ 0 & 0 & 1 & 0 & 1 & 0 \\ 0 & 1 & 1 & 0 & 0 & 1 \end{bmatrix}$ (b)	$Q = \begin{bmatrix} -1 & 0 & 1 & 1 & 0 & 0 \\ 0 & 0 & -1 & 0 & 1 & 0 \\ 0 & 1 & 1 & 0 & 0 & 1 \end{bmatrix}$
(c) $Q = \begin{bmatrix} 1 & 0 & 1 & 1 & 0 & 0 \\ 0 & 0 & -1 & 0 & 1 & 0 \\ 0 & 1 & 1 & 0 & 0 & 1 \end{bmatrix}$ (d)	$Q = \begin{bmatrix} 0 & 0 & 0 & 1 & 0 & 0 \\ 0 & 1 & 0 & 0 & 0 & -1 \\ 1 & 0 & 1 & 1 & -1 & -1 \end{bmatrix}$
(c) $Q = \begin{bmatrix} 0 & 0 & -1 & 0 & 1 & 0 \end{bmatrix}$ (d	0 = 0 + 0 + 0 + 0 + 0 = -1
Ans : (a)	
49. For a two-port network, V_1 and V_2 given by	
$V_1 = 60I_1 + 20I_2$	
$V_2 = 20I_1 + 40I_2$	
The Y – parameters of the network are	
$Y_{11} = 20 \times 10^{-3}$	$Y_{11} = -10 \times 10^{-3}$
	$Y = 20 \times 10^{-3}$
(a) $Y_{12} = -10 \times 10^{-3}$ $Y_{21} = -10 \times 10^{-3}$ (b)	$Y_{12} = 20 \times 10^{-3}$ $Y_{21} = 20 \times 10^{-3}$
$Y_{22} = 30 \times 10^{-3}$	$Y_{22} = -30 \times 10^{-3}$
$Y_{11} = 10 \times 10^{-3}$	$Y_{11} = -20 \times 10^{-3}$
(c) $Y_{12} = -20 \times 10^{-3}$ SINCE (d) $Y_{21} = -20 \times 10^{-3}$	$Y_{12} = 10 \times 10^{-3}$
(c) $\frac{12}{V} = -20 \times 10^{-3}$ (d)	$V = 10 \times 10^{-3}$
$Y_{22} = 30 \times 10^{-3}$	$Y_{22} = -30 \times 10^{-3}$
Ans: (a)	

- The h_{11} and h_{22} of a standard T-network with series impedance 2Ω and 7Ω , and shut 50. branch impedance of 3 Ω are
 - (a) 5 Ω and 10 mho respectively
 - (c) 5 Ω and 0.1 mho respectively
- (b) 10 Ω and 5 mho respectively
- (d) 10 Ω and 0.2 mho respectively

51. For the 2-port network shown the parameter Y_{12} is Equal to?



Ans: (d)

52. The Transmission parameter matrix [T] for an ideal Transformer of $n_1 : n_2$ is given by

(a)
$$\begin{bmatrix} \frac{n_1}{n_2} & 1\\ 0 & \frac{n_2}{n_1} \end{bmatrix}$$
 (b) $\begin{bmatrix} \frac{n_1}{n_2} & 0\\ 0 & \frac{n_2}{n_1} \end{bmatrix}$ (c) $\begin{bmatrix} \frac{n_1}{n_2} & 1\\ 0 & \frac{-n_2}{n_1} \end{bmatrix}$ (d) $\begin{bmatrix} \frac{n_1}{n_2} & 0\\ 1 & -\frac{n_2}{n_1} \end{bmatrix}$

Ans: (b)

- 53. A 2-port network has parameters of ABCD. If all the impedences in the network are Doubled, then
 - (a) A and D are remain un changed B is doubled and C is halved
 - (b) A, B, C and D are all Doubled
 - (c) A and D are doubled C and B remain unchanged
 - (d) A and D remain unchanged C is doubled and B is halved.

Ans: (a)

54. The conditions under which a passive 2-port network represented by ABCD if reciprocal and symmetrical are

(a) $AD - BC = 1; A = C$	(b) $AD - BC = 0; A = D$
(c) $AD - BC = 1; D = A$	(d) $AD - BC = 0; C = B$

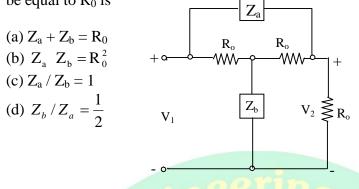
Ans: (c)

55. The maximum power that a 12 V DC source with an internal resistance of 2 Ω can supply to a resistive load is (a) 72 W (b) 48 W (c) 24 W (d) 18 W

Ans: (d)

56. A two-terminal network consists of a coil having inductance L and resistance R shunted by a capacitance C. The poles and zeros of the driving-point impedance

function $Z(\omega)$ are located as poles at $-\frac{1}{2} \pm \frac{\sqrt{3}}{2}$ and zero at -I. If Z(0) = 1, the values of R, L and C are (a) 1 Ω , 1 H and 1 μ F (c) 1 Ω , 1 μ H and 1 F (d) 1 $k\Omega$, 1 H and 1 F Ans : (b) 57. The condition under which the input impedance at port 1 for the above network will be equal to R_0 is



Ans : (b)

58. If the potential difference between points A(1, 0, 0) and B(2, 0, 0) is 10 V, determine d for point C(d, 0, 0), when V_{BC} is 6 V in a uniform field. (a) 1m (b) 2 m (c) 6 m (d) 5 m

Ans: (d)

59. There are three charges, which are given by $Q_1 = 1\mu C$, $Q_2 = 2\mu C$ and $Q_3 = 3\mu C$. The field due to each charge at a point P in free space is $(a_x + 2a_y - a_z)$, $(a_y + 3a_z)$ and $(2a_x - a_y)$ newtons /coulomb. The total field at the point P due to all three charges is given by

(a) $1.6a_x + 2.2a_y + 2.5a_z$ newtons/coulomb

- (b) $0.3a_x + 0.2a_y + 0.2a_z$ newtons/coulomb
- (c) $3a_x + 2a_y + 2a_z$ newtons/coulomb
- (d) $0.6a_x + 0.2a_y + 0.5a_z$ newtons/coulomb

Ans: (c)

60. The credit of defining the following current is due to Maxwell (a) Conduction current (b) Drift current

- (a) Conduction current(c) Displacement current
- (d) Diffusion current

Ans: (c)

- 61. In a digital frequency meter, the Schmitt trigger is used for
 - (a) converting sinusoidal waveforms into rectangular pulses
 - (b) scaling of sinusoidal waveforms
 - (c) providing timebase
 - (d) triggering a start pulse

Ans: (a)

- 62. The following transducer(s) may employ strain gauge as a secondary transducer (a) Load cell only
 - (b) Load cell and torquemeter only
 - (c) Load cell, torquemeter and accelerometer only
 - (d) Load cell, torquemeter, accelerometer and flowmeter

Ans : (b)

A Q-meter is supplied with an oscillator having a 500 mV output voltage. While testing an unknown inductor, the voltage across the variable capacitor of the Q-meter, measured by a digital voltmeter, is obtained as 10 V. The Q-factor of the inductor is (a) 5 (b) 10 (c) 20 (d) 0.05

Ans: (c)

- 64. Lissajous pattern shown in a double-beam cathode-ray oscilloscope screen for two sinusoidal voltages of equal magnitude and of the same frequency but of phase shift of 30° electrical is
 - (a) a circle
 - (b) a straight line at 45° in the first and third quadrant
 - (c) an ellipse in the first and third quadrant
 - (d) an ellipse in the second and fourth quadrant

Ans: (c)

- 65. A d'Arsonval meter of 100Ω DC coil and 0-1 mA sensitivity gives full-scale reading of 10 A on using an external resistance of
- (a) 100 Ω (b) 10 Ω (c) 0.01 Ω (d) 0.001 Ω

Ans: (c)

- 66. The null balance potentiometric measurement of voltage technique in *not* capable of measuring
 - (a) DC voltage
 - (b) AC voltage
 - (c) voltage with higher accuracy and sensitivity as compared to deflection-type instrument
 - (d) dynamic and transient voltage changes

Ans : (d)

- 67. The following type of instrument can be used for measuring AC voltage of the highest frequency with reasonable accuracy
 - (a) Electrodynamometer
 - (c) Thermal-thermoelectric
- (b) Moving-iron
- (d) Rectifier

Ans: (c)

- 68. To increase the range of a voltmeter
 - (a) a low resistance in series is connected with the voltmeter
 - (b) a low resistance in parallel is connected with the voltmeter
 - (c) a high resistance in series is connected with the voltmeter
 - (d) a high resistance in parallel is connected with the voltmeter

Ans: (c)

- 69. For the recording of very fast random signals, the most suitable instrument would be (a) dual-trace (b) sampling oscilloscope
 - (c) real-time spectrum analyzer
- (b) sampling oscilloscope(d) scanning-type spectrum analyzer

- 70. A resistance is measured by a voltmeter-ammeter method using DC excitation and a voltmeter of very high resistance connected directly across the unknown resistance. If the voltmeter and ammeter are subject to maximum error of $\pm 2.4\%$ and $\pm 1.0\%$ respectively, then the magnitude of maximum error in the value of resistance obtained from the measurement is nearly (a) 1.4% (b) 1.7% (c) 2.4% (d) 3.4% Ans: (d) 71. During measurement of voltage and current in a load, ammeter and voltmeter are connected in series and across the load respectively. If ammeter and voltmeter positions are interchanged by mistake, then (a) voltmeter will be damaged (b) ammeter will be damaged (c) both the meters will be damaged (d) both the meters will be safe Ans: (b) 72. The directivity of a $\lambda/2$ long wire antenna is (d) $\sqrt{2}$ (a) 1.5 (b) 1.66 (c) 2Ans: (b) 73. The ratio of the transverse electric field to the transverse magnetic field is called as (a) waveguide impedance (b) waveguide wavelength (c) phase velocity (d) Poynting vector Ans: (a) 74. Consider a rectangular waveguide of internal dimensions $8 \text{ cm} \times 4 \text{ cm}$. Assuming an H_{10} mode of propagation, the critical wavelength would be (a) 8 cm (b) 16 cm (c) 4 cm (d) 32 cm Ans: (b) $-\omega^2\mu\epsilon$ represents the propagation constant in a rectangular 75. waveguide for (a) TE waves only (b) TM waves only (d) TE and TM waves (c) TEM waves
- Ans: (d)
- 76. With the symbols having their standard meaning, cut-off frequency (frequency below which wave propagation will not occur) for a rectangular waveguide is

(a)
$$\frac{1}{\sqrt{\mu\epsilon}}\sqrt{\left(\frac{m\pi}{a}\right) + \left(\frac{n\pi}{b}\right)}$$

(b) $\frac{1}{2\pi\sqrt{\mu\epsilon}}\sqrt{\left(\frac{m\pi}{a}\right)^2 + \left(\frac{n\pi}{b}\right)^2}$
(c) $\frac{1}{2\pi\sqrt{\mu\epsilon}}\left(\frac{m\pi}{a}\right) + \left(\frac{n\pi}{b}\right)$
(d) $\frac{1}{\sqrt{-\nu}}\sqrt{\left(\frac{mf}{a}\right)^2 + \left(\frac{nf}{b}\right)^2}$

Ans: (b)

77.	A plane wave travelling in a medium of $\varepsilon_r = 1$, $\mu_r = 1$ (free space) has an electric field intensity of $100\sqrt{\pi}$ V/m. Determine the total energy density of this magnetic field. (a) 13.9 nJ/m ³ (b) 27.8 nJ/m ³ (c) 139 nJ/m ³ (d) 278 nJ/m ³	1
Ans :		
78.	A $\lambda/4$ line, shorted at one end, presents impedance at the other end equal to (a) Z_0 (b) $\sqrt{2}Z_0$ (c) ∞ (d) 0	
Ans :	Where Z_0 is characteristic impedance of the line. c)	
79.	A 75 Ω transmission line is first short-terminated and the minima locations are noted When the short is replaced by a resistive load R _L , the minima locations are not altere and the VSWR is measured to be 3. The value of R _L is (a) 25 Ω (b) 50 Ω (c) 225 Ω (d) 250 Ω	
Ans :	a)	
80.	For a plane wave propagating in an unbounded medium (say, free space), the minimum angle between electric field and magnetic field vectors is (a) 0^0 (b) 60^0 (c) 90^0 (d) 180^0	
Ans :	c)	
81.	Moving-coil permanent magnet instruments can be used for the measurement of(a) AC and DC(b) AC only(c) DC only(d) half-wave rectified DC	
Ans :	c)	
82.	For controlling the vibration of the disc of an AC energy meter, damping torque is produced by (a) eddy current (b) chemical effect	
Ans :	(c) electrostatic effect (d) magnetic effect a)	
83.	Analog inputs are converted to digital outputs using op-amps as comparators. Assuming a 5-bit digital output, the number of comparators required would be (a) 32 (b) 31 (c) 64 (d) 63	
Ans :		
84.	The value of <i>n</i> for the n-bit A/D converter required to convert an analog input in the range of 0 to 5 volts to an accuracy of 10 mV is (a) 8 (b) 9 (c) 7 (c) 6	
Ans :		
85. Ans :	One of the following can act as an inverse transducer (a) Electrical resistance potentiometer (b) LVDT (c) Piezoelectric crystal (d) Capacitive transducer	

86. Two strain gauges are used to measure strain in a cantilever, one gauge is mounted on the top of the cantilever and the other is placed at the bottom. The two strain gauges form two arms of Wheatstone's bridge. This bridge configuration is called (a) a quarter bridge (b) a half bridge (c) a full bridge (d) a null bridge Ans:(b)87. A Hall effect transducer is generally used for the measurement of (b) current (c) displacement (a) power (d) voltage Ans: (c) 88. A digital linear displacement transducer normally uses (a) straight binary code (b) binary coded decimal (d) hexadecimal code (c) Gray code Ans: (c) 89. The following transducer is used for accurate and precise measurement of temperature (a) Thermistor (b) Thermocouple (Alumel / Chromel) (c) Semiconductor temperature sensor chip (d) Platinum resistance thermometer **Ans : (d)** 90. Electrical voltage-based telemetering schemes used for short distances must necessarily have (a) low current level only (b) small signal power only (c) high signal to noise ratio $\left(\frac{S}{N} >> 2\right)$ only (d) All of the above Ans: (d)91. Electrical positional system telemetering uses for transmission of signal in (a) two wires only (b) two or three wires only (c) two or three or four wires only (d) two or three or four or even five wires Ans:(b)

Direction:

Each of the following **nine (9)** items consists of two statements, one labelled as 'Statement (I)' and the other as 'Statement (II)'. You are to examine these two statements carefully and select the answers to these items using code given below: Code:

(a) Both Statement (I) and Statement (II) are individually true and Statement (II) is the correct explanation of Statement (I)

(b) Both Statement (I) and Statement (II) are individually true but Statement (II) is *not* the correct explanation of Statement (I)

(c) Statement (I) is true but Statement (II) is false

(d) Statement (I) is false but Statement (II) is true

92. Statement (I):

All substances except ferro-magnetic materials which can form permanent magnets, exhibit magnetic effects.

Statement (II):

Their magnetic effect is due to alignment of dipoles when subjected to an external electromagnetic field.

Ans : (d)

93. Statement (I):

Concentration of acceptor atoms in the region between isolation islands in a monolithic integrated circuit will be much higher than in the p-type substrate.

Statement (II):

The higher density is provided to prevent the depletion region of the reverse-biased isolation to substrate junction from extending into the p^+ -type material.

Ans: (a)

94. Statement (I):

The gate of MOSFET is insulated from the body of FET by deposition of a very thin fragile layer of SiO_2 over the substrate.

Statement (II):

The device is therefore called as an insulated gate field-effect transistor (IGFET).

Ans: (a)

95. Statement (I):

Z-transform approach is used to analyze the discrete time systems and is also called as pulse transfer function approach.

Statement (II):

The sampled signal is assumed to be a train of impulses whose strengths, or areas, are equal to the continuous time signal at the sampling instants.

Ans: (a)

96. Statement (I):

Lossless network functions have only imaginary zeros and poles with only negative real parts.

Statement (II):

Lossless network functions obey the separation property.

Ans : (d)

97. Statement (I):

Resistance hygrometer is a good humidity transducer. **Statement (II):**

Resistance hygrometer has a sensing element and absorbs or gives up moisture till

equilibrium is reached with ambient water vapour pressure.

98. Statement (I):

Dual-slope A/D converter is the most preferred A/D conversion approach in digital multimeters.

Statement (II):

Dual-slope A/D converter provides high accuracy in A/D conversion, while at the same time suppressing the hum effect on the input signal.

Ans: (a)

99. Statement (I):

RF voltage is measured by rectifying the alternating voltage first and then amplifying the resulting DC output.

Statement (II):

Amplification of RF signals is itself a very difficult task.

Ans: (a)

100. Statement (I):

Digital universal counter timer is used to measure time period and frequency of various circuits which are assembled together to form one complete block.

Statement (II):

Digital counters use logic gates which are selected and controlled by a single front panel switch known as function switch which can be in either frequency or time-base mode.

Ans: (a)

- 101. Diodes are used to compensate which of the following transistor circuit parameters? 1. I_{CO}
 - 2. V_{BE}
 - 3.β

(a) 1 an	d 2 only	(b) 2 and 3 only	(c) 1 and 3 only	(d) 1, 2 and 3
2 X				

Ans: (a)

- 102. The relative values of the forward conduction voltage for a p-n junction diode, a Red LED and a Schottky barrier diode are
 - (a) Schottky voltage drop > p n junction diode drop > Red LED drop
 - (b) Red LED drop > p-n junction diode drop > Schottky voltage drop
 - (c) *p-n* junction diode drop > Schottky voltage drop > Red LED drop
 - (d) Schottky voltage drop > Red LED drop > p-n junction diode drop

Ans: (b)

- 103. A freewheeling diode in a phase-controlled rectifier
 - (a) improves the line power factor (b) is responsible for additional reactive power
 - (c) prevents inverse operation (d) is responsible for additional harmonics

Ans: (a)

- 104. The following equation describes a linear time-varying discrete time system
 - (a) y(k + 2) + ky(k + 1) + y(k) = u(k)(b) $y(k + 2) + ky^{2}(k + 1) + y(k) = u(k)$ (c) y(k + 2) + 3y(k + 1) + 2y(k) = u(k)(d) $y(k + 2) + y^{2}(k + 1) + ky(k) = u(k)$.

Ans: (a)

105. Hall effect is useful for the measurement of a semiconductor's

- (a) mobility, carrier concentration and temperature
- (b) type (n-type or p-type), conductivity and temperature
- (c) type (n-type or p-type), mobility and carrier concentration
- (d) mobility, conductivity and temperature

Ans: (c)

- 106. Given:
 - N(E) : Density of states
 - F(E): Probability that a quantum state with energy E is occupied by an electron
 - E_c : Energy level of conduction band

The expression $\int_{E_c}^{\infty} N(E) f(E) dE$ gives

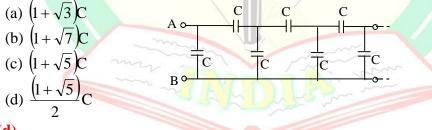
- (a) minimum number of electrons in conduction band
- (b) concentration of electrons in conduction band
- (c) energy of electron concentration in conduction band
- (d) conductivity of electrons in conduction band

Ans: (b)

- 107. Non-polar electrolytic capacitors
 - (a) are used for applications in AC circuits without any DC polarizing voltage
 - (b) contain two capacitors connected in series with opposing polarities
 - (c) Both (a) and (b) are correct
 - (d) Both (a) and (b) are wrong

Ans: (a)

108. The effective capacitance across AB of the infinite ladder shown in the above figure is

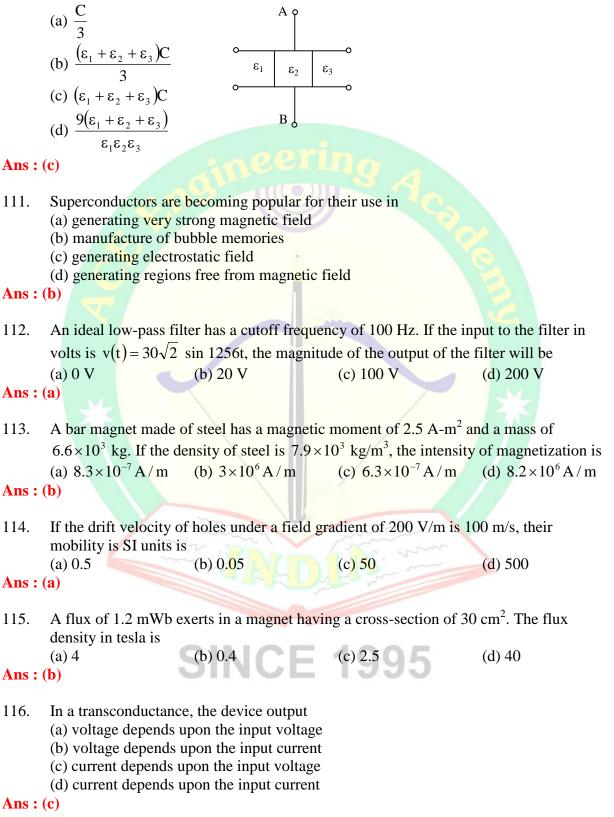


Ans: (d)

109. A capacitor of capacitance C is charged by connecting it to a battery of e.m.f. E.. The capacitor is now disconnected and reconnected to the battery with the polarity reversed. The heat developed in the connecting wires is

(a)
$$0.5 \text{ CE}^2$$
 (b) $\overline{\text{CE}}^2$ (c) 2 CE^2 (d) 3 CE^2
(s; (c)

110. The space between the plates of a parallel-plate capacitor of capacitance C is filled with three dielectric slabs of identical size as shown in the figure. If dielectric constants are ε_1 , ε_2 , and ε_3 , the new capacitance is



117. A potential barrier of 0.50 V exists across a p-n junction. If the depletion region is 5.0×10^{-7} m wide, what is the intensity of the electric field in this region? (a) $1.0 \times 10^6 \text{ W/m}$ (b) 2.5×10^{-7} V/m

(a) 1.0×10 V/m	(b) 2.3×10 V/III
(c) 2.5×10^{-7} V/m	(d) 2.5×10^8 V/m
• (a)	

Ans: (a)

The concentration of hole-electron pairs in pure silicon at T = 300 K is 7×10^{15} per 118. cubic meter. Antimony is doped into silicon in a proportion of 1 atom to 10^7 atoms. Assuming that half of the impurity atoms contribute electrons in the conduction band, the factor by which the number of charge carries increases due to doping (the number of silicon atoms per cubic meter is 5×10^{28}) is (b) 0.5×10^{21}

(a) 14×10^{15}

(c) 2.5×10^{21}

(d) 1.8×10^5

Ans: (c)

119. A piece of writing paper that is 10 cm wide, 15 cm long and 0.05 mm thick has a dielectric strength of 8 kV/mm. If it is placed between two copper plates and subjected to an increasing voltage, it will break down at (a) 8 kV (b) 4 kV (c) $0.4 \, \text{kV}$ (d) 0.8 kV

Ans: (c)

120. Match List-I with List-II and select the correct answer using the code given below the List:

	List	-I 🍯				List	-II			
A. Electrostriction						1. Converse of Seebeck effect				
B. Io	nic cor	nductivi	ty		2. Re	everse e	effect of	piezoe	lectricit	y
C. Pe	eltier he	eat			3. Co	onverse	effect of	of magn	etostric	tion
D. V	illari ef	ffect			4. Co	onducti	vity of i	nsulato	rs	
Code	e:				14					
	Α	В	С	D		Α	B	C	D	
(a)	2	4	-1-	3	(b)	3	_4	- 1	2	
(c)	2	1~	4,	3	(d)	3	1	-4	2	
: (a)										

Ans : (a)

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